



General Information	
Series	B45196P
Dielectric	MnO ₂ Tantalum
Style	SMD Chip
Description	SMD, Molded, High Temperature
Features	High Temperature, Automotive
RoHS	Yes
Termination	Tin
Qualifications	AEC-Q200
AEC-Q200	Yes
Notes	Obsolete.

Dimensions	
Footprint	3216
L	3.2mm +/-0.2mm
W	1.6mm +/-0.2mm
H	1.6mm +/-0.2mm
S	0.8mm +/-0.3mm
F	1.2mm +/-0.1mm
K	1.3mm TYP

Specifications	
Capacitance	2.2 uF
Capacitance Tolerance	20%
Voltage DC	10 VDC (85C), 7.97 VDC (125C), 6.7 VDC (150C)
Temperature Range	-55/+150°C
Rated Temperature	85°C
Dissipation Factor	4.5%
Failure Rate	N/A
Resistance	4.6 Ohms (100kHz)
Ripple Current	127.7 mAmps (25C), 114.9 mAmps (85C), 51.1 mAmps (125C)
Leakage Current	0.5 uA

Packaging Specifications	
Packaging	T&R, 330mm
Packaging Quantity	9000